

Erratum: “Low-resistance GaN tunnel homojunctions with 150 kA/cm^2 current and repeatable negative differential resistance” [Appl. Phys. Lett. 108, 131103 (2016)]

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Erratum: “Low-resistance GaN tunnel homojunctions with 150 kA/cm² current and repeatable negative differential resistance” [Appl. Phys. Lett. **108**, 131103 (2016)]

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We have noticed a mistake in reporting the voltage value at 20 A/cm². Reported voltage value of 3 V should be corrected as 3.3 V.¹ This value is stated in the first sentence of the last page and in the last paragraph of the last page and in the caption of Fig. 5. We apologize to the readers of the

Applied Physics Letter for any confusion that might have been caused.

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